

## GALLIUM ARSENIDE

## Nanopowder

Nanoparticles research is currently one of the most active branches of science with many of applications in various field. Gallium arsenide is a semiconductor with excellent electronic properties. gallium arsenide nanoparticles. Gallium is a Block P, Period 4 element, while arsenic is a Block P, Period 4 element. Gallium arsenide is a semiconductor with excellent electronic properties. The morphology of gallium arsenide nanoparticles is gray cubic crystals. Gallium arsenide nanoparticles are graded as toxic and dangerous for the environment. Gallium arsenide (GaAs) is a compound of gallium and arsenic. It is a vital semiconductor and is commonly used to manufacture devices such as infrared emitting diodes, laser diodes, integrated circuits at microwave frequencies, and photovoltaic cells.

GaAs

**CAS** 1303-00-0

# Quick Facts

Product : Gallium Arsenide Nanopowder

Stock No : NS6130-12-000342

CAS : 1303-00-0 Color : Grey

Form : Powder

### **TECHNICAL** Specification

 APS
 : 80-100nm

 Purity
 : 99.99%

 Molecular Weight
 : 144.64g/mol

 Density
 : 5.3 g/cm³

 Melting Point
 : 1400°C

### **APPLICATIONS**

- In the manufacture of devices such as monolithic microwave integrated circuits, infrared light-emitting diodes, microwave frequency integrated circuits, solar cells, laser diodes, and optical windows
  - Gallium arsenide nanowires can be used for high technology applications such as electronics, optics, and photovoltaics.



#### **Packing Sizes:**

25Gms, 50Gms, 100Gms, 500Gms & Bulk Orders

80-100nm













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INTELLIGENT MATERIALS PVT LTD







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